



#### 450V N-CHANNEL ENHANCEMENT MODE MOSFET

## **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub>	I <sub>D</sub> T <sub>A</sub> = +25°C
450V	50Ω @ V <sub>GS</sub> = 10V	140mA

### **Description**

This new generation trench MOSFET features a unique structure combining the benefits of low on-resistance and fast switching, making it ideal for high efficiency power management applications.

### **Applications**

Off-line Power Supply Start-up Circuitry

## **Features and Benefits**

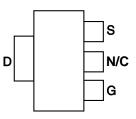
- High Voltage
- Low On-resistance
- Fast Switching Speed
- Low Gate Drive
- Low Threshold
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

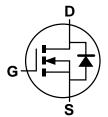
- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish @3)
- Weight: 0.112 grams (Approximate)







Pin Out - Top



**Equivalent Circuit** 

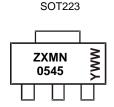
#### Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXMN0545G4TA	ZXMN0545	7	12	1,000
ZXMN0545G4TC	ZXMN0545	13	12	4,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain < 900ppm bromine, < 900ppm chlorine (< 1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



ZXMN0545 = Product Type Marking Code YWW = Date Code Marking Y or  $\overline{Y}$  = Last Digit of Year (ex: 5 = 2015) WW or  $\overline{WW}$  = Week Code (01~53)



## **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	$V_{DSS}$	450	V
Gate-Source Voltage	$V_{GSS}$	±20	V
Continuous Drain Current (V <sub>GS</sub> = 10V; T <sub>A</sub> = +25°C) (Note 5)	I <sub>D</sub>	140	mA
Pulsed Drain Current (Note 7)	I <sub>DM</sub>	600	mA
Continuous Source Current (Body Diode) (Note 6)	Is	140	mA
Pulsed Source Current (Body Diode) (Note 7)	I <sub>SM</sub>	600	mA

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation at T <sub>A</sub> = +25°C (Note 5)	Б	2.0	W
Linear Derating Factor	P <sub>D</sub>	1.6	mW/°C
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>0JA</sub>	62.5	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	$R_{ heta JA}$	32	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

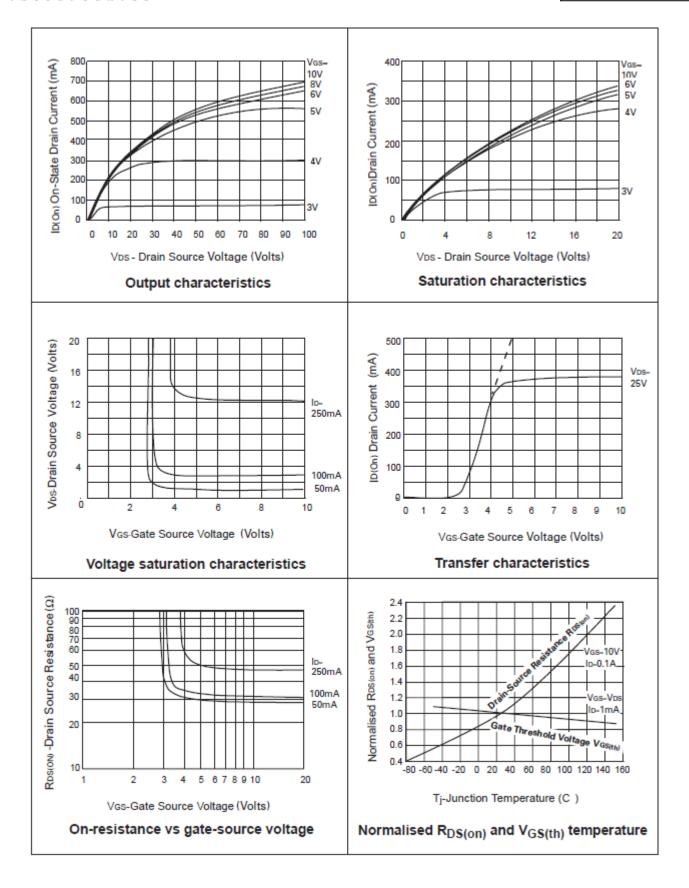
## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	450	-	-	V	$V_{GS} = 0V$ , $I_D = 1mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	-	-	10 400	μA	V <sub>DS</sub> = 450V, V <sub>GS</sub> = 0V V <sub>DS</sub> = 405V, V <sub>GS</sub> = 0V, T = +125°C	
Gate-Source Leakage	I <sub>GSS</sub>	-	-	20	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS	•						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	-	3	V	$V_{DS} = V_{GS}$ , $I_D = 1mA$	
Static Drain-Source On-Resistance (Note 8)	R <sub>DS(ON)</sub>	-	-	50	Ω	$V_{GS} = 10V, I_D = 100mA$	
Forward Transconductance (Notes 8 & 10)	g <sub>fs</sub>	100	-	-	mS	$V_{DS} = 25V, I_D = 100mA$	
On-State Drain Current (Note 8)	I <sub>D(ON)</sub>	150	-	-	mA	V <sub>DS</sub> = 25V, V <sub>GS</sub> = 10V	
DYNAMIC CHARACTERISTICS (Note 11)	DYNAMIC CHARACTERISTICS (Note 11)						
Input Capacitance (Note 10)	C <sub>iss</sub>	-	-	70	pF	V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V, f = 1.0MHz	
Output Capacitance (Note 10)	Coss	-	-	10	рF		
Reverse Transfer Capacitance (Note 10)	C <sub>rss</sub>	-	-	4	pF		
Turn-On Delay Time (Notes 9 & 10)	t <sub>D(ON)</sub>	-	-	7	ns	V <sub>DD</sub> = 25V, I <sub>D</sub> = 100mA	
Turn-On Rise Time (Notes 9 & 10)	t <sub>R</sub>	-	-	7	ns		
Turn-Off Delay Time (Notes 9 & 10)	t <sub>D(OFF)</sub>	-	-	16	ns		
Turn-Off Fall Time (Notes 9 & 10)	t <sub>F</sub>	-	-	10	ns		

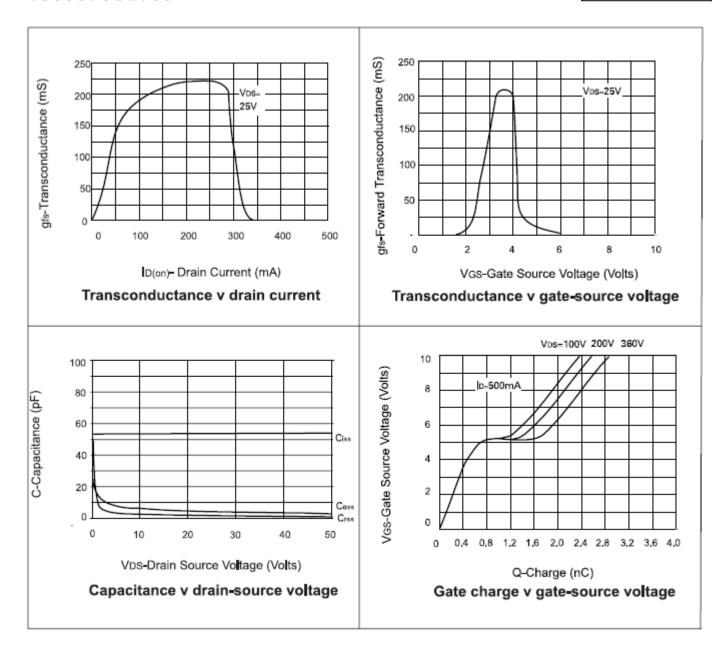
Notes:

- 5. For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
  6. For a device surface mounted on FR4 PCB measured at t ≤ 5 secs.
  7. Repetitive rating pulse width limited by maximum junction temperature. Refer to Transient Thermal Impedance graph.
- 8. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.
- 9. Switching characteristics are independent of operating junction temperature.
- 10. Sample test.
- 11. For design aid only, not subject to production testing.





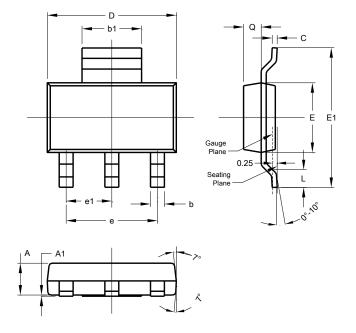






## **Package Outline Dimensions**

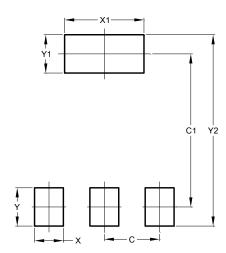
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223				
Dim	Min	Max	Тур	
Α	1.55	1.65	1.60	
A1	0.010	0.15	0.05	
b	0.60	0.80	0.70	
b1	2.90	3.10	3.00	
С	0.20	0.30	0.25	
D	6.45	6.55	6.50	
Е	3.45	3.55	3.50	
E1	6.90	7.10	7.00	
е	-	-	4.60	
e1	-	-	2.30	
L	0.85	1.05	0.95	
q	0.84	0.94	0.89	
All Dimensions in mm				

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Υ	1.60
Y1	1.60
Y2	8.00



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